IXYS
A Littelfuse Technology

Date: 10th January 2023

Data Sheet Issue: 2

Rectifier Diode

Types W0790LG620 to W0790LG680

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	6200-6800	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	6300-6900	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T_{sink}=55°C, (note 2)	790	A
$I_{F(AV)M}$	Maximum average forward current. T_{sink}=100°C, (note 2)	535	A
$I_{F(AV)M}$	Maximum average forward current, T_{sink}=100°C, (note 3)	310	A
$I_{F(RMS)M}$	Nominal RMS forward current, T_{sink}=25°C, (note 2)	1460	A
$I_{F(d.c.)}$	D.C. forward current, T_{sink}=25°C, (note 4)	1325	A
I_{FSM}	Peak non-repetitive surge t_p=10ms, V_{rm}=0.6V_{RRM}, (note 5)	7000	A
I_{FSM2}	Peak non-repetitive surge t_p=10ms, V_{rm}≤10V, (note 5)	7700	A
I^2t	I^2t capacity for fusing t_p=10ms, V_{rm}=0.6V_{RRM}, (note 5)	245×10^3	A^2s
I^2t	I^2t capacity for fusing t_p=10ms, V_{rm}≤10V, (note 5)	296×10^3	A^2s
$T_{j\,op}$	Operating temperature range	-40 to +150	°C
T_{stg}	Storage temperature range	-55 to +150	°C

Notes:-
1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
4) Double side cooled.
5) Half-sinewave, 150°C T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	3.8	I_{TM}=2625A	V
V_{T0}	Threshold voltage	-	-	0.98		V
r_T	Slope resistance	-	-	1.06		mΩ
I_{RRM}	Peak reverse current	-	-	50	Rated V_{RRM}	mA
I_{RRM}	Peak reverse current	-	-	2	Rated V_{RRM}, T_j=25°C	mA
Q_{rr}	Total recovered charge	-	5815	6450	I_{FM}=1000A, t_p=1ms, di/dt=10A/µs, V_r=100V	µC
Q_{ra}	Reverse recovery charge (50% chord)	-	2211	-		µC
I_{rm}	Reverse recovery current	-	137	-		A
t_{rr}	Reverse recovery time (50% chord)	-	33	-		µs
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.0394	Double side cooled	K/W
		-	-	0.0707	Anode side cooled	K/W
				0.0898	Cathode side cooled	K/W
F	Mounting force	10	-	20		kN
W_t	Weight	-	400	-		g

Notes:-

1) Unless otherwise indicated T_j=150°C.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
62	6200	6300	4150
65	6500	6600	4350
68	6800	6900	4550

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Repetitive dv/dt

Standard dv/dt is 1000V/µs.

5.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

6.0 Computer Modelling Parameters

6.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}{}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$

and:

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j\max} - T_C$$

Where V_{T0}=0.98V, r_T=1.06mΩ,

R_{th} = Supplementary thermal impedance, see table below.

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave Double Side Cooled	0.0480	0.0445	0.0425	0.03940
Square wave Anode Side Cooled	0.0797	0.0759	0.0738	0.0707
Square wave Cathode Side Cooled	0.0983	0.0950	0.0929	0.0898
Sine wave Double Side Cooled	0.0451	0.0422	0.0396	
Sine wave Anode Side Cooled	0.0762	0.0732	0.0707	
Sine wave Cathode Side Cooled	0.0957	0.0928	0.0901	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

6.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented by a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients		150°C Coefficients	
A	0.110406435	A	0.101875316
B	0.200243555	B	0.168859960
C	7.131702×10^{-4}	C	1.068433×10^{-3}
D	-1.513197×10^{-2}	D	-9.060147×10^{-3}

6.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where *p = 1* to *n and:*

n = number of terms in the series
t = Duration of heating pulse in seconds
r_t = Thermal resistance at time t
r_p = Amplitude of p^{th} term
τ_p = Time Constant of r^{th} term

The coefficients for this device are shown in the table below:

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	0.02350677	0.01080067	3.111832×10^{-3}	1.946426×10^{-3}
τ_p	1.261361	0.1407335	0.01999451	2.677464×10^{-3}

D.C. Anode Side Cooled					
Term	1	2	3	4	5
r_p	0.04517370	0.01092023	0.01002468	2.972535×10^{-3}	1.644544×10^{-3}
τ_p	6.555359	0.7723341	0.1155237	0.01578855	2.018220×10^{-3}

D.C. Cathode Side Cooled				
Term	1	2	3	4
r_p	0.06840358	0.01444154	4.487340×10^{-3}	2.389196×10^{-3}
τ_p	7.458694	0.2510212	0.03334104	3.271107×10^{-3}

7.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{RM} chord as shown in Fig. 1

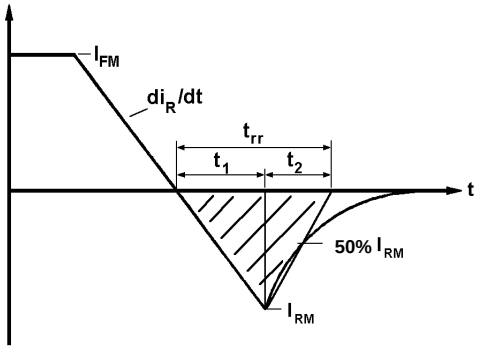


Fig. 1

(ii) Q_{rr} is based on a 150μs integration time i.e.

$$Q_{rr} = \int_0^{150\mu s} i_{rr}.dt$$

(ii)

$$K\ Factor = \frac{t_1}{t_2}$$

Curves

Figure 1 – Forward characteristics of Limit device

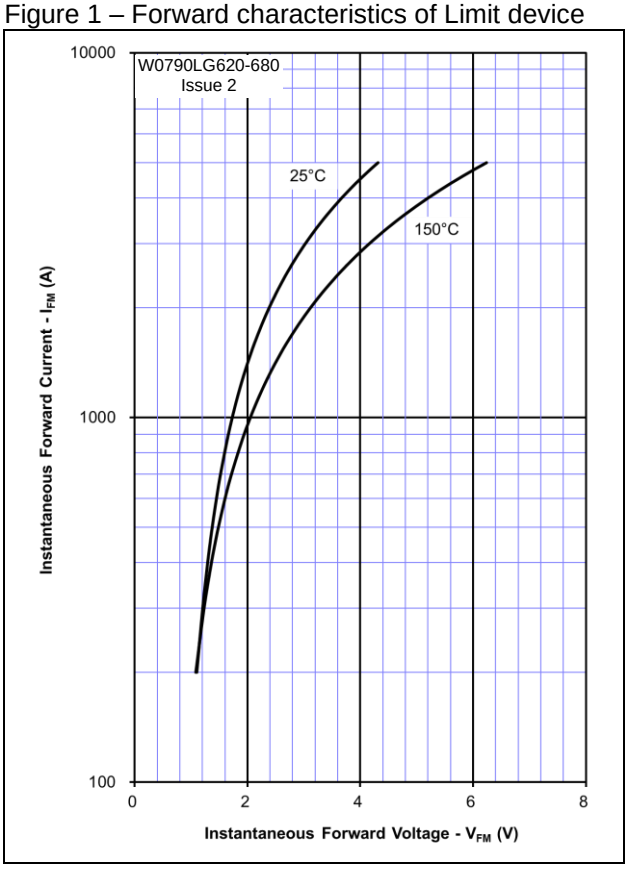


Figure 2 – Transient Thermal Impedance

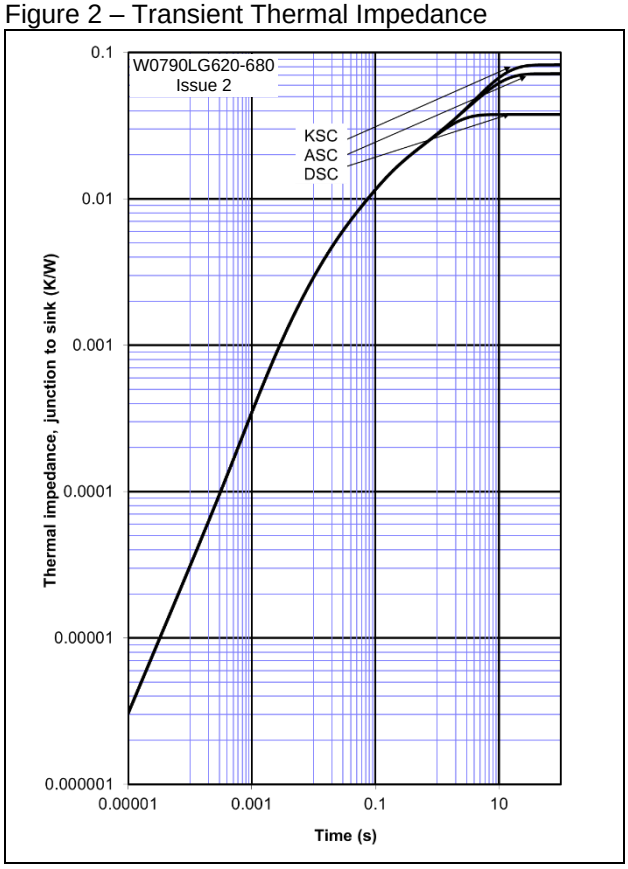


Figure 3 – Maximum surge and I^2t Ratings

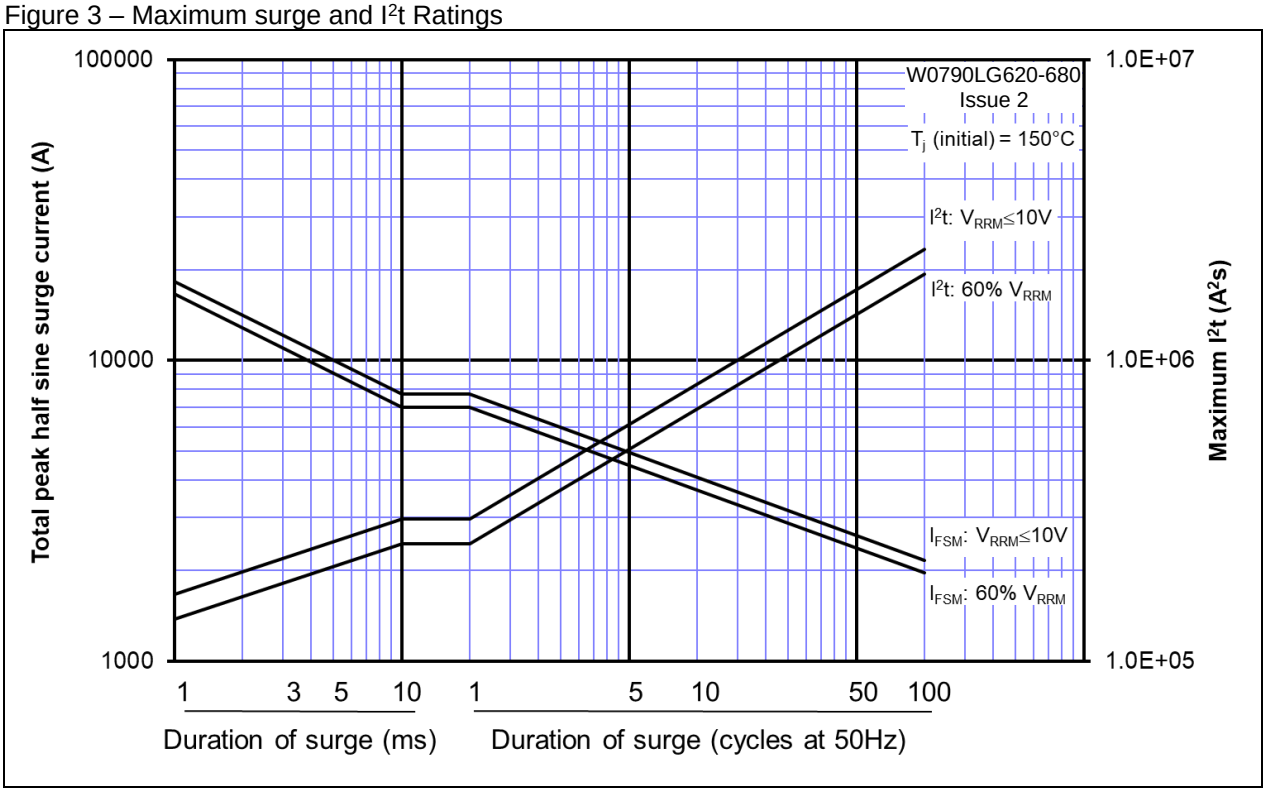


Figure 4 – Total recovered charge, Q_{rr}

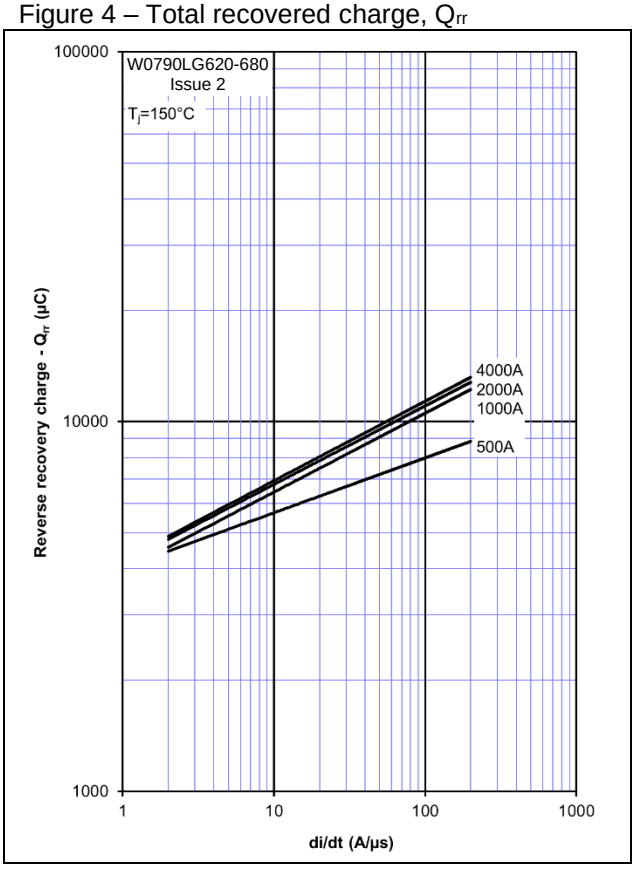


Figure 5 – Recovered charge (50% chord), Q_{ra}

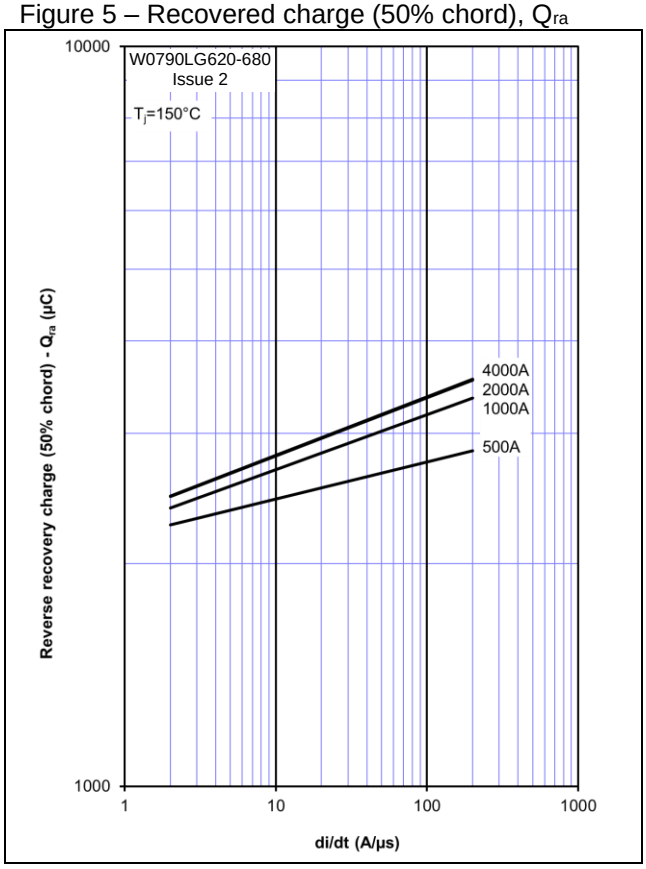


Figure 6 – Peak reverse recovery current, I_{rm}

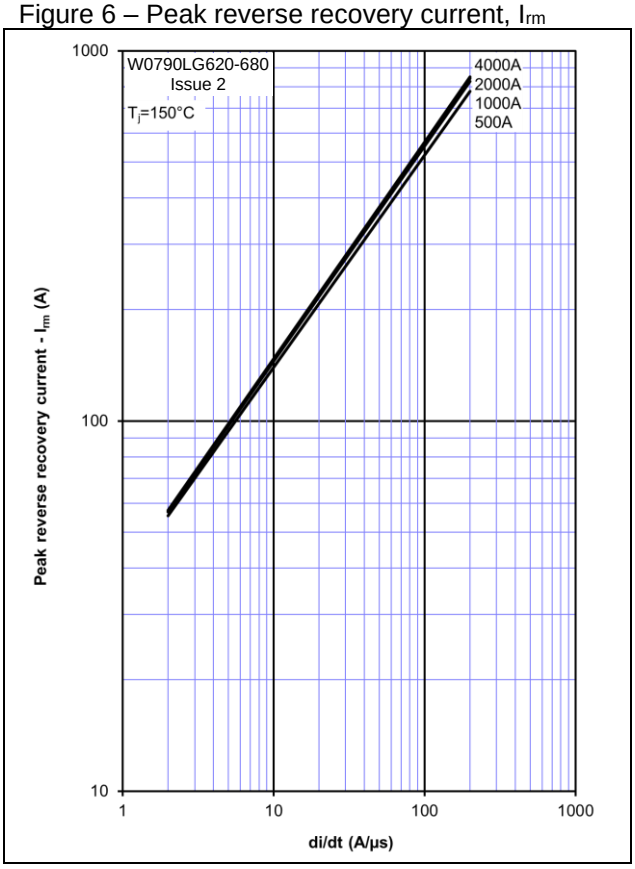


Figure 7 – Reverse recovery time (50% chord), t_{rr}

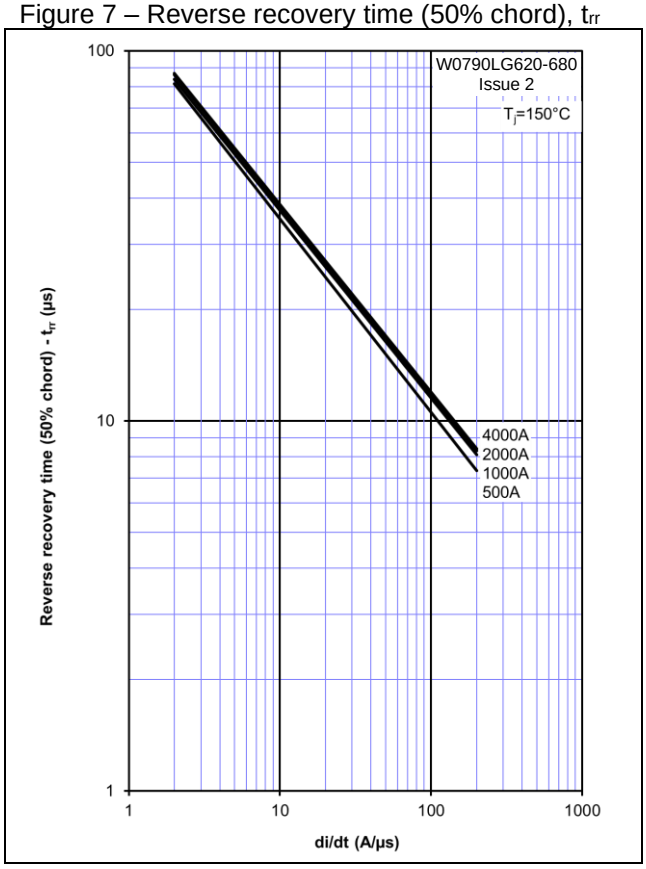


Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

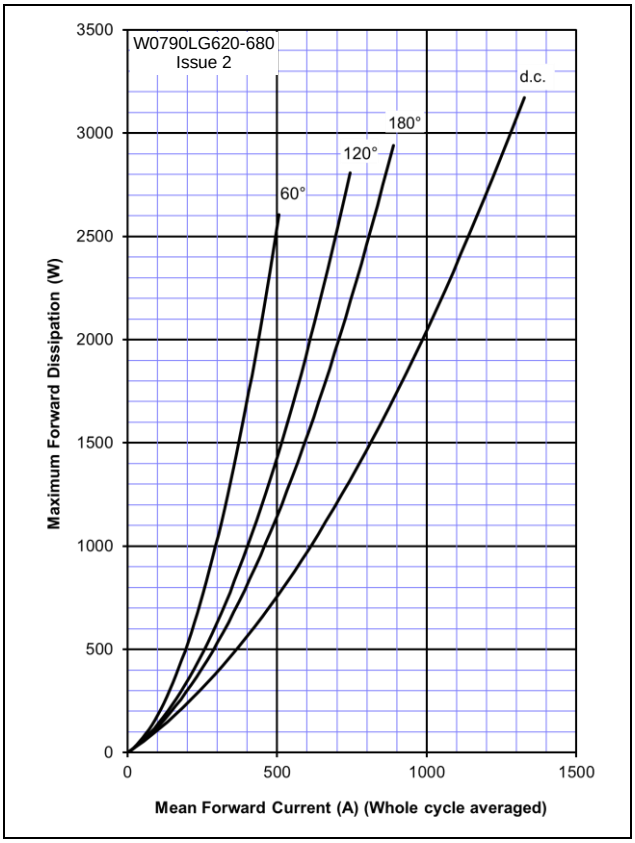


Figure 9 – Forward current vs. Heatsink temperature - Double Side Cooled

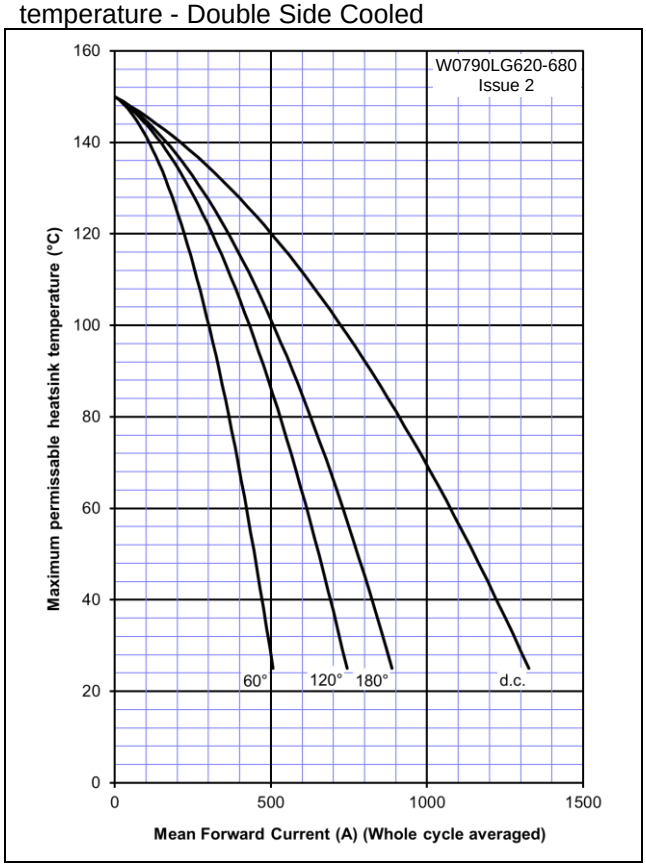


Figure 10 – Forward current vs. Power dissipation – Cathode Side Cooled

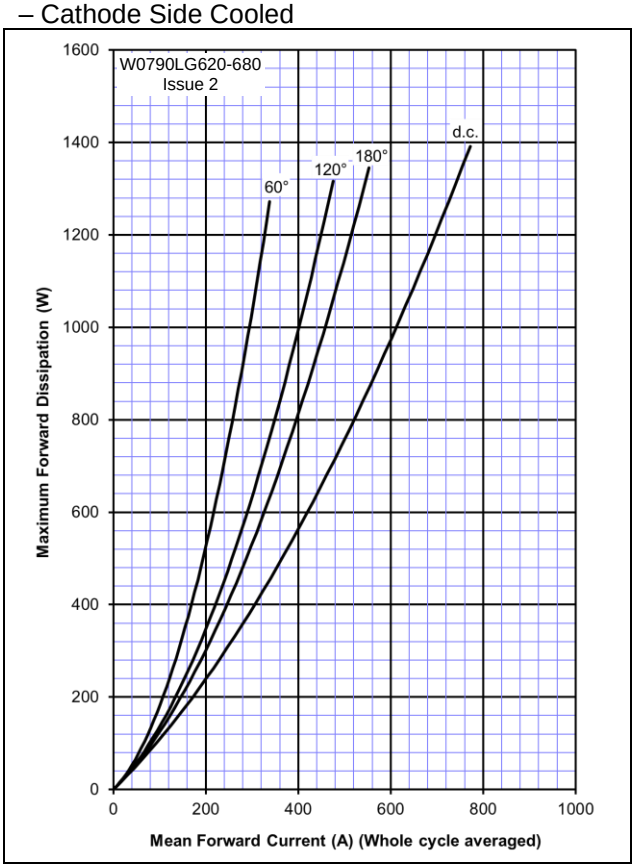
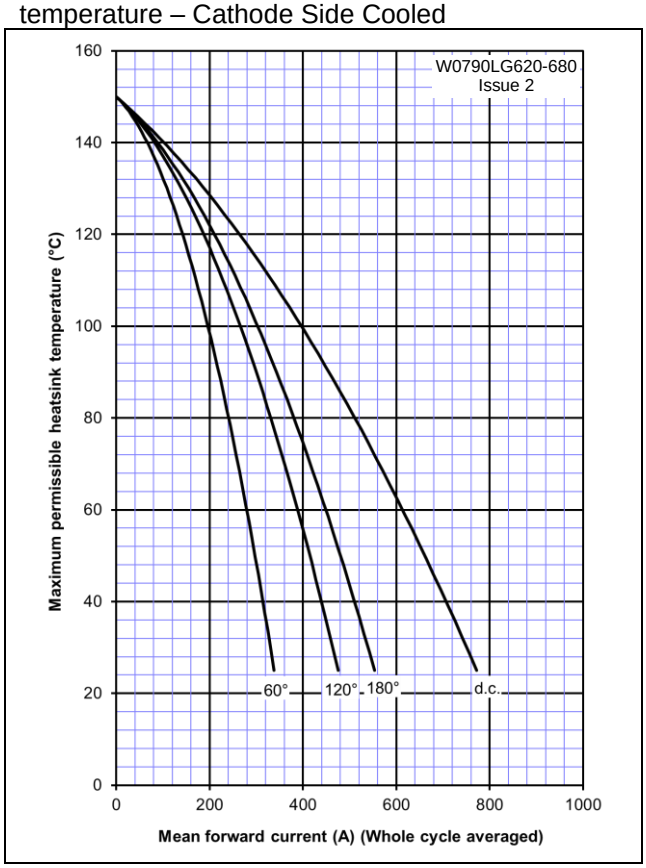
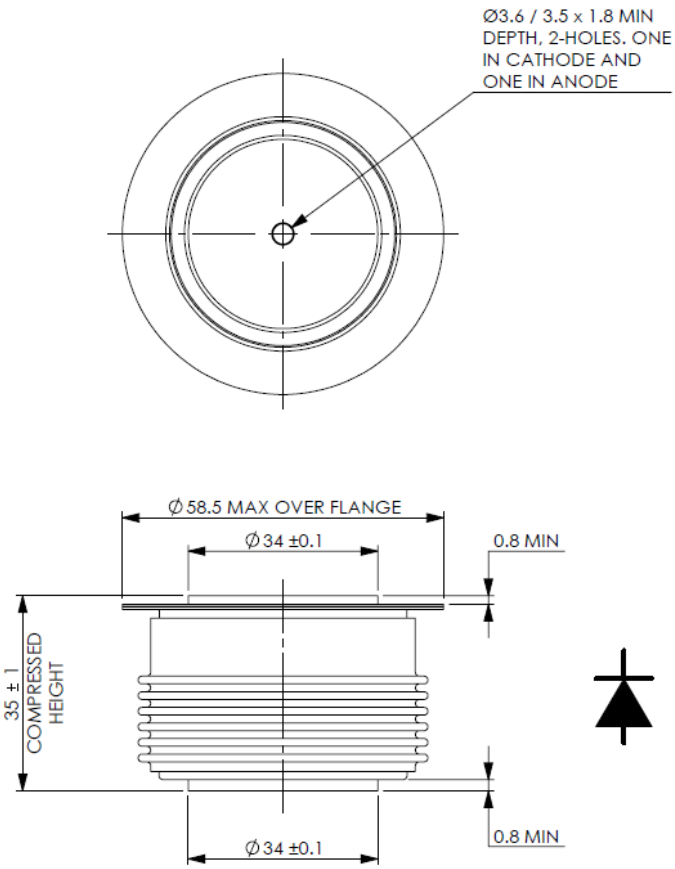


Figure 11 – Forward current vs. Heatsink temperature – Cathode Side Cooled



Outline Drawing & Ordering Information



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ORDERING INFORMATION		(Please quote 10 digit code as below)	
W0790	**LG**	**♦♦**	**0**
Fixed Type Code	Fixed Outline Code	Voltage code V_{DRM}/100 62-68	Fixed turn-off time code

Order code: W0790LG680 – 6800V V_{RRM}, 35mm clamp height capsule

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